针对与 bq2419x 充电器控制器一起使用的电池管理单元 Impedance Track™ 电量计

查询样品: **bq27531-G1**

特性

- 针对单节锂离子电池应用的电池电量计
- 驻留在系统主板上
- 基于已获专利的 **Impedance Track™** 技术的电池电量计
  - 可为准确续航时间预测建模电池放电曲线
  - 可针对电池老化、电池自放电以及温度/速率低效情况进行自动调节
  - 低值感应电阻器（**5mΩ** 至 **20mΩ**）
- 具有可定制充电配置的电池充电器管理器
  - 可根据温度配置的充电电压和电流
  - 可选健康状态 **(SoH)** 和基于多级别的充电配置
- 无主机自主电池管理系统
  - 精简的软件开销可实现平台间的轻松可移植性以及更短代工生产 **(OEM)** 设计周期
  - 更高的可靠性和安全性

- 运行时间提升
  - 阻抗跟踪 **(Impedance Track)** 技术带来了更长的运行时间
  - 针对充电器终止的更加严密的精度控制
  - 经改进的再充电阀值
- 智能充电-定制的和自适应充电配置
  - 基于 **SoH** 的充电器控制
  - 温度水平充电 **(TLC)**
- 针对 **bq2419x** 单节开关模式电池充电器的电池充电器控制
  - 独立充电解决方案
  - 出厂模式性能
- **400kHz I²C™** 用于与系统微处理器端口相连接的接口
- 采用 **15** 引脚 **NanoFree™ (CSP)** 封装内

应用范围

- 智能手机、功能型手机和平板电脑
- 数码相机与数码摄像机
- 手持终端设备
- **MP3** 或多媒体播放器

说明

德州仪器 (TI) 的bq27531-G1系统侧锂离子电池管理单元是一款微控制器外设，此外设提供针对单节锂离子电池组的 Impedance Track™ 电量检测和充电控制。 此器件只需很少的系统微处理器固件开发。 与 bq2419x 单节开关模式充电器一起使用，bq27531-G1管理一个嵌入式电池（不可拆卸）或一个可拆卸电池组。

bq27531-G1采用已获专利的 Impedance Track™ 算法支持电量检测，可提供诸如剩余电池容量 (mAh)，充电状态 (%)，续航时间（分钟），电池电压 (mV)，温度 (°C) 以及健康状况 (%) 等信息。

通过bq27531-G1进行电池电量监测只需将 PACK+ (P+)，PACK- (P-) 以及热敏电阻 (T) 连接至可拆卸电池组或嵌入式电池电路。 CSP 选项采用尺寸为 2.61mm × 1.96mm 的 15 焊球封装，引线间距为 0.5mm。 它是空间受限应用的理想选择。

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Impedance Track, NanoFree are trademarks of Texas Instruments.
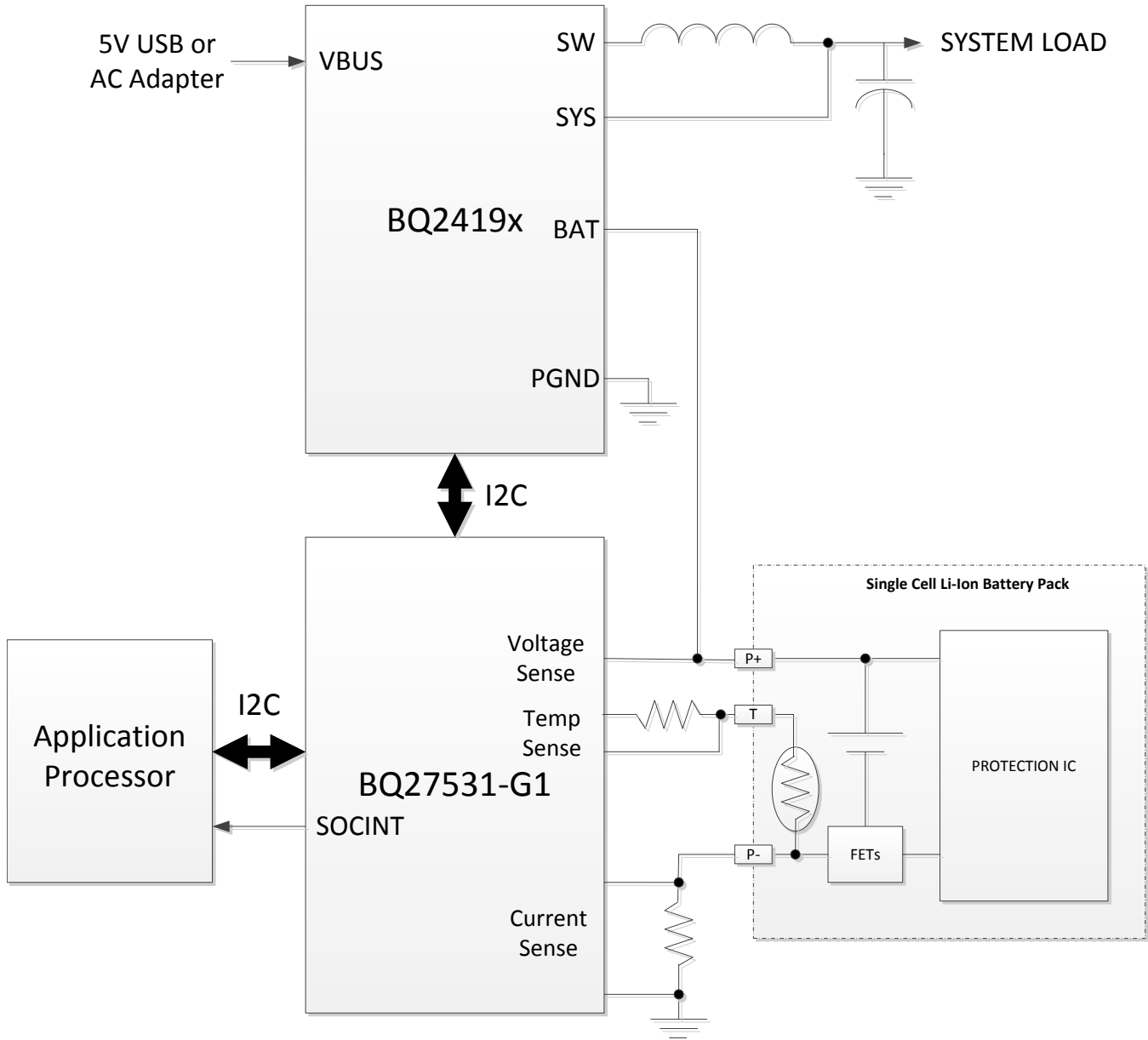I²C is a trademark of NXP B.V. Corp Netherlands.

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

TYPICAL APPLICATION

DEVICE INFORMATION

AVAILABLE OPTIONS

PART NUMBER	FIRMWARE VERSION	PACKAGE	T$_A$	COMMUNICATION FORMAT	TAPE and REEL QUANTITY
bq27531YZFR-G1	1.02 (0x0102)	CSP-15	–40°C to 85°C	I^{2}C	3000
bq27531YZFT-G1					250

THERMAL INFORMATION

THERMAL METRIC[1]		bq27531-G1	UNITS
		YZF (15 PINS)	
θ_{JA}	Junction-to-ambient thermal resistance	70	°C/W
$\theta_{JC(top)}$	Junction-to-case(top) thermal resistance	17	
θ_{JB}	Junction-to-board thermal resistance	20	
ψ_{JT}	Junction-to-top characterization parameter	1	
ψ_{JB}	Junction-to-board characterization parameter	18	
$\theta_{JC(bottom)}$	Junction-to-case(bottom) thermal resistance	n/a	

(1)　有关传统和新的热 度量的更多信息，请参阅 *IC* 封装热度量应用报告， SPRA953。
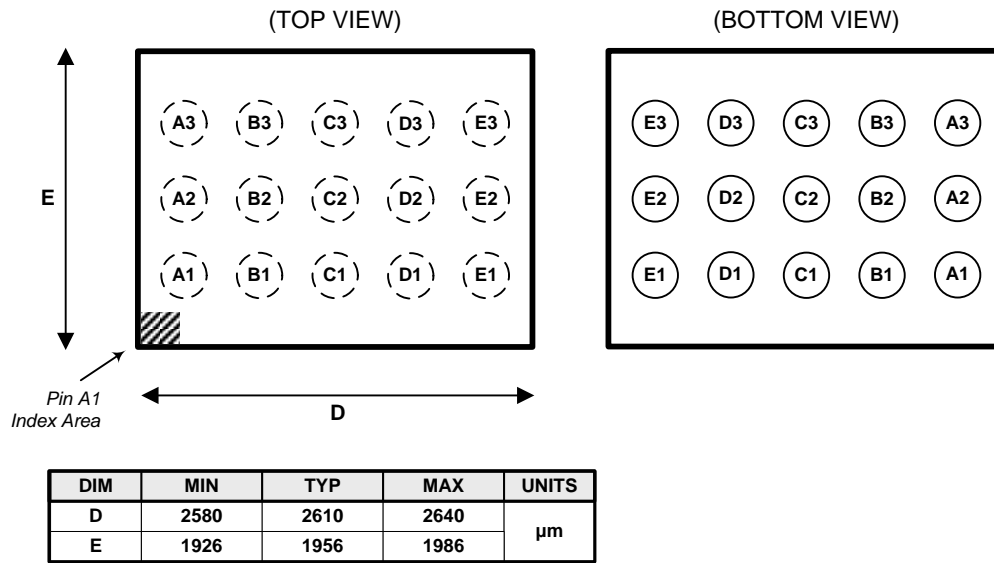
PIN ASSIGNMENT AND PACKAGE DIMENSIONS

(TOP VIEW)   (BOTTOM VIEW)

DIM	MIN	TYP	MAX	UNITS
D	2580	2610	2640	μm
E	1926	1956	1986	

Table 1. PIN FUNCTIONS

PIN NAME	PIN NO.	TYPE	DESCRIPTION
SRP	A1	IA	Analog input pin connected to the internal coulomb counter where SRP is nearest the PACK– connection. Connect to 5-mΩ to 20-mΩ sense resistor.
SRN	B1	IA	Analog input pin connected to the internal coulomb counter where SRN is nearest the Vss connection. Connect to 5-mΩ to 20-mΩ sense resistor.
V_{SS}	C1, C2	P	Device ground
V_{CC}	D1	P	Regulator output and bq27531-G1 power. Decouple with 1μF ceramic capacitor to Vss.
REGIN	E1	P	Regulator input. Decouple with 0.1μF ceramic capacitor to Vss.
SOC_INT	A2	I/O	SOC state interrupts output. Generates a pulse as described in *bq27531-G1 Technical Reference Manual*. Open drain output.
BSCL	B2	O	Battery Charger clock output line for chipset communication. Push-pull output.
CE	D2	I	Chip Enable. Internal LDO is disconnected from REGIN when driven low. **Note:** CE has an internal ESD protection diode connected to REGIN. Recommend maintaining $V_{CE} \leq V_{REGIN}$ under all conditions.
BAT	E2	I	Cell-voltage measurement input. ADC input. Recommend 4.8V maximum for conversion accuracy.
SCL	A3	I	Slave I²C serial communications clock input line for communication with system (Master). Open-drain I/O. Use with 10kΩ pull-up resistor (typical).
SDA	B3	I/O	Slave I²C serial communications data line for communication with system (Master). Open-drain I/O. Use with 10kΩ pull-up resistor (typical).
BSDA	C3	I/O	Battery Charger data line for chipset communication. Push-pull output.
TS	D3	IA	Pack thermistor voltage sense (use 103AT-type thermistor). ADC input.
BI/TOUT	E3	I/O	Battery-insertion detection input. Power pin for pack thermistor network. Thermistor-multiplexer control pin. Use with pull-up resistor >1MΩ (1.8 MΩ typical).

ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) [1]

PARAMETER		VALUE	UNIT
V_{REGIN}	Regulator input range	−0.3 to 5.5	V
		−0.3 to 6.0 [2]	V
V_{CE}	CE input pin	−0.3 to V_{REGIN} + 0.3	V
V_{CC}	Supply voltage range	−0.3 to 2.75	V
V_{IOD}	Open-drain I/O pins (SDA, SCL, SOC_INT)	−0.3 to 5.5	V
V_{BAT}	BAT input pin	−0.3 to 5.5	V
		−0.3 to 6.0 [2]	V
V_I	Input voltage range to all other pins (BI/TOUT, TS, SRP, SRN, BSDA, BSCL)	−0.3 to V_{CC} + 0.3	V
ESD	Human-body model (HBM), BAT pin	1.5	kV
	Human-body model (HBM), all other pins	2	
T_A	Operating free-air temperature range	−40 to 85	°C
T_{stg}	Storage temperature range	−65 to 150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Condition not to exceed 100 hours at 25 °C lifetime.

RECOMMENDED OPERATING CONDITIONS

T_A = -40°C to 85°C, V_{REGIN} = V_{BAT} = 3.6V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{REGIN}	Supply voltage	No operating restrictions	2.8		4.5	V
		No FLASH writes	2.45		2.8	
C_{REGIN}	External input capacitor for internal LDO between REGIN and V_{SS}	Nominal capacitor values specified. Recommend a 5% ceramic X5R type capacitor located close to the device.		0.1		µF
C_{LDO25}	External output capacitor for internal LDO between V_{CC} and V_{SS}		0.47	1		µF
t_{PUCD}	Power-up communication delay			250		ms

SUPPLY CURRENT

T_A = 25°C and V_{REGIN} = V_{BAT} = 3.6V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{CC} [1]	Normal operating-mode current	Fuel gauge in NORMAL mode. I_{LOAD} > *Sleep Current*		118		µA
I_{SLP+} [1]	Sleep+ operating mode current	Fuel gauge in SLEEP+ mode. I_{LOAD} < *Sleep Current*		62		µA
I_{SLP} [1]	Low-power storage-mode current	Fuel gauge in SLEEP mode. I_{LOAD} < *Sleep Current*		23		µA
I_{HIB} [1]	Hibernate operating-mode current	Fuel gauge in HIBERNATE mode. I_{LOAD} < *Hibernate Current*		8		µA

(1) Specified by design. Not production tested.

DIGITAL INPUT AND OUTPUT DC CHARACTERISTICS

T_A = –40°C to 85°C, typical values at T_A = 25°C and V_{REGIN} = 3.6 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OL}	Output voltage, low (SCL, SDA, SOC_INT, BSDA, BSCL)	I_{OL} = 3 mA			0.4	V
$V_{OH(PP)}$	Output voltage, high (BSDA, BSCL)	I_{OH} = –1 mA	V_{CC} – 0.5			V
$V_{OH(OD)}$	Output voltage, high (SDA, SCL, SOC_INT)	External pullup resistor connected to V_{CC}	V_{CC} – 0.5			
V_{IL}	Input voltage, low (SDA, SCL)		–0.3		0.6	V
	Input voltage, low (BI/TOUT)	BAT INSERT CHECK MODE active	–0.3		0.6	
V_{IH}	Input voltage, high (SDA, SCL)		1.2			V
	Input voltage, high (BI/TOUT)	BAT INSERT CHECK MODE active	1.2		V_{CC} + 0.3	
$V_{IL(CE)}$	Input voltage, low (CE)	V_{REGIN} = 2.8 to 4.5V			0.8	V
$V_{IH(CE)}$	Input voltage, high (CE)		2.65			
I_{lkg} [1]	Input leakage current (I/O pins)				0.3	µA

(1) Specified by design. Not production tested.

POWER-ON RESET

T_A = –40°C to 85°C, typical values at T_A = 25°C and V_{REGIN} = 3.6 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IT+}	Positive-going battery voltage input at V_{CC}		2.05	2.15	2.20	V
V_{HYS}	Power-on reset hysteresis		45	115	185	mV

2.5V LDO REGULATOR

T_A = –40°C to 85°C, C_{LDO25} = 1µF, V_{REGIN} = 3.6V (unless otherwise noted)

	PARAMETER	TEST CONDITION	MIN	NOM	MAX	UNIT
V_{REG25}	Regulator output voltage (V_{CC})	2.8V ≤ V_{REGIN} ≤ 4.5V, I_{OUT} ≤ 16mA [1]	2.3	2.5	2.6	V
		2.45V ≤ V_{REGIN} < 2.8V (low battery), I_{OUT} ≤ 3mA	2.3			V

(1) LDO output current, I_{OUT}, is the total load current. LDO regulator should be used to power internal fuel gauge only.

INTERNAL CLOCK OSCILLATORS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
f_{OSC}	High Frequency Oscillator			8.389		MHz
f_{LOSC}	Low Frequency Oscillator			32.768		kHz

ADC (TEMPERATURE AND CELL MEASUREMENT) CHARACTERISTICS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{ADC1}	Input voltage range (TS)		V_{SS} – 0.125		2	V
V_{ADC2}	Input voltage range (BAT)		V_{SS} – 0.125		5	V
$V_{IN(ADC)}$	Input voltage range		0.05		1	V
G_{TEMP}	Internal temperature sensor voltage gain			–2		mV/°C
t_{ADC_CONV}	Conversion time				125	ms
	Resolution		14		15	bits
$V_{OS(ADC)}$	Input offset			1		mV
Z_{ADC1} [1]	Effective input resistance (TS)		8			MΩ
Z_{ADC2} [1]	Effective input resistance (BAT)	bq27531-G1 not measuring cell voltage	8			MΩ
		bq27531-G1 measuring cell voltage		100		kΩ
$I_{lkg(ADC)}$ [1]	Input leakage current				0.3	µA

(1) Specified by design. Not tested in production.

INTEGRATING ADC (COULOMB COUNTER) CHARACTERISTICS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{SR}	Input voltage range, $V_{(SRP)}$ and $V_{(SRN)}$	$V_{SR} = V_{(SRP)} – V_{(SRN)}$	–0.125		0.125	V
t_{SR_CONV}	Conversion time	Single conversion		1		s
	Resolution		14		15	bits
$V_{OS(SR)}$	Input offset			10		µV
INL	Integral nonlinearity error			±0.007	±0.034	% FSR
$Z_{IN(SR)}$ [1]	Effective input resistance		2.5			MΩ
$I_{lkg(SR)}$ [1]	Input leakage current				0.3	µA

(1) Specified by design. Not tested in production.

DATA FLASH MEMORY CHARACTERISTICS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{DR} [1]	Data retention		10			Years
	Flash-programming write cycles[1]		20,000			Cycles
$t_{WORDPROG}$ [1]	Word programming time				2	ms
I_{CCPROG} [1]	Flash-write supply current			5	10	mA
$t_{DFERASE}$ [1]	Data flash master erase time		200			ms
$t_{IFERASE}$ [1]	Instruction flash master erase time		200			ms
$t_{PGERASE}$ [1]	Flash page erase time		20			ms

(1)   Specified by design. Not production tested

I²C-COMPATIBLE INTERFACE COMMUNICATION TIMING CHARACTERISTICS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_r	SCL/SDA rise time				300	ns
t_f	SCL/SDA fall time				300	ns
$t_{w(H)}$	SCL pulse duration (high)		600			ns
$t_{w(L)}$	SCL pulse duration (low)		1.3			µs
$t_{su(STA)}$	Setup for repeated start		600			ns
$t_{d(STA)}$	Start to first falling edge of SCL		600			ns
$t_{su(DAT)}$	Data setup time		100			ns
$t_{h(DAT)}$	Data hold time		0			ns
$t_{su(STOP)}$	Setup time for stop		600			ns
$t_{(BUF)}$	Bus free time between stop and start		66			µs
f_{SCL}	Clock frequency [1]				400	kHz

(1)   If the clock frequency (f_{SCL}) is > 100 kHz, use 1-byte write commands for proper operation. All other transactions types are supported at 400 kHz. (Refer to I²C INTERFACE and I²C Command Waiting Time)
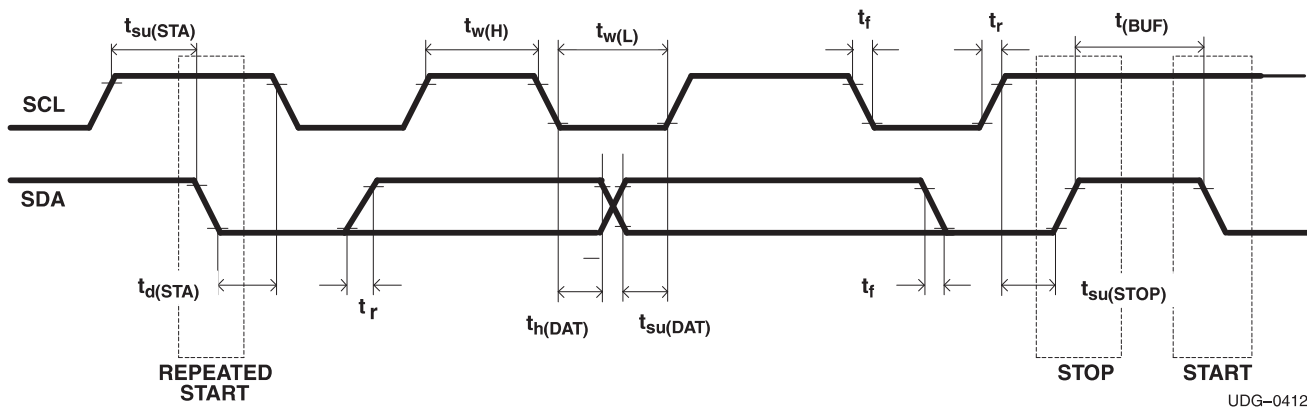
Figure 1. I²C-Compatible Interface Timing Diagrams

GENERAL DESCRIPTION

The bq27531-G1 accurately predicts the battery capacity and other operational characteristics of a single Li-based rechargeable cell. It can be interrogated by a system processor to provide cell information, such as time-to-empty (TTE), and state-of-charge (SOC) as well as SOC interrupt signal to the host.

The bq27531-G1 can control a bq2419x Charger IC without the intervention from an application system processor. Using the bq27531-G1 and bq2419x chipset, batteries can be charged with the typical constant-current, constant voltage (CCCV) profile or charged using a Multi-Level Charging (MLC) algorithm.

Information is accessed through a series of commands, called *Standard Commands*. Further capabilities are provided by the additional *Extended Commands* set. Both sets of commands, indicated by the general format *Command( )*, are used to read and write information contained within the device control and status registers, as well as its data flash locations. Commands are sent from system to gauge using the bq27531-G1's I^{2}C serial communications engine, and can be executed during application development, pack manufacture, or end-equipment operation.

Cell information is stored in the device in non-volatile flash memory. Many of these data flash locations are accessible during application development. They cannot, generally, be accessed directly during end-equipment operation. Access to these locations is achieved by either use of the bq27531-G1's companion evaluation software, through individual commands, or through a sequence of data-flash-access commands. To access a desired data flash location, the correct data flash subclass and offset must be known.

The key to the bq27531-G1 high-accuracy gas gauging prediction is Texas Instrument's proprietary Impedance Track™ algorithm. This algorithm uses cell measurements, characteristics, and properties to create state-of-charge predictions that can achieve less than 1% error across a wide variety of operating conditions and over the lifetime of the battery.

The device measures battery charge/discharge activity by monitoring the voltage across a small-value series sense resistor (5 mΩ to 20 mΩ typ.) located between the system's Vss and the battery's PACK- terminal. When a cell is attached to the device, cell impedance is computed, based on cell current, cell open-circuit voltage (OCV), and cell voltage under loading conditions.

The device external temperature sensing is optimized with the use of a high accuracy negative temperature coefficient (NTC) thermistor with R25 = 10.0kΩ ±1%, B25/85 = 3435K ± 1% (such as Semitec NTC 103AT). The bq27531-G1 can also be configured to use its internal temperature sensor. When an external thermistor is used, a 18.2k pull up resistor between BI/TOUT and TS pins is also required. The bq27531-G1 uses temperature to monitor the battery-pack environment, which is used for fuel gauging and cell protection functionality.

To minimize power consumption, the device has different power modes: NORMAL, SLEEP, SLEEP+, HIBERNATE, and BAT INSERT CHECK. The bq27531-G1 passes automatically between these modes, depending upon the occurrence of specific events, though a system processor can initiate some of these modes directly.

For complete operational details, refer to *bq27531-G1 Technical Reference Manual*.

NOTE

FORMATTING CONVENTIONS IN THIS DOCUMENT:

Commands: *italics* with parentheses and no breaking spaces, e.g., *RemainingCapacity( )*

Data flash: *italics*, **bold**, and *breaking spaces*, e.g., **Design Capacity**

Register bits and flags: brackets and *italics*, e.g., *[TDA]*

Data flash bits: brackets, *italics* and **bold**, e.g., ***[LED1]***

Modes and states: ALL CAPITALS, e.g., UNSEALED mode.

DATA COMMANDS

STANDARD DATA COMMANDS

The bq27531-G1 uses a series of 2-byte standard commands to enable system reading and writing of battery information. Each standard command has an associated command-code pair, as indicated in Table 2. Because each command consists of two bytes of data, two consecutive I^{2}C transmissions must be executed both to initiate the command function, and to read or write the corresponding two bytes of data. Additional details are found in the *bq27531-G1 Technical Reference Manual*.

Table 2. Standard Commands

NAME	COMMAND CODE	UNITS	SEALED ACCESS	UNSEALED ACCESS
Control( )	0x00 / 0x01	N/A	R/W	R/W
AtRate( )	0x02 / 0x03	mA	R/W	R/W
AtRateTimeToEmpty( )	0x04 / 0x05	Minutes	R	R/W
Temperature( )	0x06 / 0x07	0.1 K	R/W	R/W
Voltage( )	0x08 / 0x09	mV	R	R/W
Flags( )	0x0a / 0x0b	N/A	R	R/W
NominalAvailableCapacity( )	0x0c / 0x0d	mAh	R	R/W
FullAvailableCapacity( )	0x0e / 0x0f	mAh	R	R/W
RemainingCapacity( )	0x10 / 0x11	mAh	R	R/W
FullChargeCapacity( )	0x12 / 0x13	mAh	R	R/W
AverageCurrent( )	0x14 / 0x15	mA	R	R/W
TimeToEmpty( )	0x16 / 0x17	Minutes	R	R/W
RemainingCapacityUnfiltered( )	0x18 / 0x19	mAh	R	R/W
StandbyCurrent( )	0x1a / 0x1b	mA	R	R/W
RemainingCapacityFiltered( )	0x1c / 0x1d	mAh	R	R/W
ProgChargingCurrent( )	0x1e / 0x1f	mA	R[1]	R[1]
ProgChargingVoltage( )	0x20 / 0x21	mV	R[1]	R[1]
FullChargeCapacityUnfiltered( )	0x22 / 0x23	mAh	R	R/W
AveragePower( )	0x24 / 0x25	mW	R	R/W
FullChargeCapacityFiltered( )	0x26 / 0x27	mAh	R	R/W
StateOfHealth( )	0x28 / 0x29	% / num	R	R/W
CycleCount( )	0x2a / 0x2b	Counters	R	R/W
StateOfCharge( )	0x2c / 0x2d	%	R	R/W
TrueSOC( )	0x2e / 0x2f	%	R	R/W
InstantaneousCurrentReading( )	0x30 / 0x31	mA	R	R/W
InternalTemperature( )	0x32 / 0x33	0.1 K	R	R/W
ChargingLevel( )	0x34 / 0x35	HEX	R	R
LevelTaperCurrent( )	0x6e / 0x6f	mA	R	R
CalcChargingCurrent( )	0x70 / 0x71	mA	R	R
CalcChargingVoltage( )	0x72 / 0x73	V	R	R

(1) Only writeable when **Charger Options [BYPASS]** is set.

Control( ): 0x00/0x01

Issuing a *Control( )* command requires a subsequent 2-byte subcommand. These additional bytes specify the particular control function desired. The *Control( )* command allows the system to control specific features of the bq27531-G1 during normal operation and additional features when the device is in different access modes, as described in Table 3. Additional details are found in the *bq27531-G1 Technical Reference Manual*.

Table 3. *Control( )* Subcommands

CNTL FUNCTION	CNTL DATA	SEALED ACCESS	DESCRIPTION
CONTROL_STATUS	0x0000	Yes	Reports the status of hibernate, IT, etc.
DEVICE_TYPE	0x0001	Yes	Reports the device type (eg: 0x0531 for bq27531)
FW_VERSION	0x0002	Yes	Reports the firmware version on the device type
HW_VERSION	0x0003	Yes	Reports the hardware version of the device type
PREV_MACWRITE	0x0007	Yes	Returns previous MAC subcommand code
CHEM_ID	0x0008	Yes	Reports the chemical identifier of the Impedance Track™ configuration
BOARD_OFFSET	0x0009	No	Forces the device to measure and store the board offset
CC_OFFSET	0x000a	No	Forces the device to measure the internal CC offset
CC_OFFSET_SAVE	0x000b	No	Forces the device to store the internal CC offset
OCV_CMD	0x000c	Yes	Request the gauge to take a OCV measurement
BAT_INSERT	0x000d	Yes	Forces the BAT_DET bit set when the *[BIE]* bit is 0
BAT_REMOVE	0x000e	Yes	Forces the BAT_DET bit clear when the *[BIE]* bit is 0
SET_HIBERNATE	0x0011	Yes	Forces CONTROL_STATUS *[HIBERNATE]* to 1
CLEAR_HIBERNATE	0x0012	Yes	Forces CONTROL_STATUS *[HIBERNATE]* to 0
SET_SLEEP+	0x0013	Yes	Forces CONTROL_STATUS *[SNOOZE]* to 1
CLEAR_SLEEP+	0x0014	Yes	Forces CONTROL_STATUS *[SNOOZE]* to 0
OTG_ENABLE	0x0015	Yes	Commands the bq2419x into USB On The Go mode
OTG_DISABLE	0x0016	Yes	Disables OTG mode at the bq2419x
DIV_CUR_ENABLE	0x0017	Yes	Makes the programmed charge current to be half of what is calculated by the gauge charging algorithm.
CHG_ENABLE	0x001A	Yes	Enable charger. Charge will continue as dictated by gauge charging algorithm.
CHG_DISABLE	0x001B	Yes	Disable charger (Set $\overline{CE}$ bit of bq2419x)
GG_CHGRCTL_ENABLE	0x001C	Yes	Enables the gas gauge to control the charger while continuosly resetting the charger watchdog
GG_CHGRCTL_DISABLE	0x001D	Yes	The gas gauge stops resetting the charger watchdog
DIV_CUR_DISABLE	0x001E	Yes	Makes the programmed charge current to be same as what is calculated by the gauge charging algorithm.
DF_VERSION	0x001F	Yes	Returns the Data Flash Version
SEALED	0x0020	No	Places device in SEALED access mode
IT_ENABLE	0x0021	No	Enables the Impedance Track™ algorithm
RESET	0x0041	No	Forces a full reset of the bq27531-G1
SHIPMODE_ENABLE	0x0050	Yes	Commands the bq2419x to turn off BATFET after a delay time programmed in dataflash so that system load does not draw power from battery
SHIPMODE_DISABLE	0x0051	Yes	Commands the bq2419x to disregard turning off BATFET before delay time or turns on commands BATFET to turn on if an VBUS had power during the SHIPMODE enabling process

CHARGER DATA COMMANDS

The charger registers are mapped to a series of single byte Charger Data Commands to enable system reading and writing of battery charger registers. During charger power up, the registers are initialized to Charger Reset State. The fuel gauge can change the values of these registers during the System Reset State.

Each of the bits in the Charger Data Commands can be read/write. It is important to note that System Access can be different from the read/write access as defined in bq2419x charger hardware. The fuel gauge may block write access to the charger hardware when the bit function is controlled by the fuel gauge exclusively. For example, the *[VREGx]* bits of *Chrgr_Voltage_Reg4* are controlled by the fuel gauge and cannot be modfied by system.

The bq27531 reads the corresponding registers of System_Stat_Reg8( ) and Fault_Reg9( ) every second to mirror the charger status. Other registers in the bq2419x are read when registers are modified by the bq27531.

Table 4. Charger Data Commands

NAME		COMMAND CODE	bq2419x Charger Memory Location	SEALED ACCESS	UNSEALED ACCESS	Refresh Rate
ChargerStatus( )	CHGRSTAT	0x74	NA	R	R	Every second
Chrgr_InCtrl_Reg0( )	CHGR0	0x75	0x00	R/W	R/W	Data Change
Chrgr_POR_Config_Reg1( )	CHGR1	0x76	0x01	R/W	R/W	Data Change
Chrgr_Current_Reg2( )	CHGR2	0x77	0x02	R/W	R/W	Data Change
Chrgr_PreTerm_Reg3( )	CHGR3	0x78	0x03	R/W	R/W	Data Change
Chrgr_Voltage_Reg4( )	CHGR4	0x79	0x04	R/W	R/W	Data Change
Chrgr_TermTimer_Reg5( )	CHGR5	0x7a	0x05	R/W	R/W	Data Change
Chrgr_IRThermal_Reg6( )	CHGR6	0x7b	0x06	R/W	R/W	Data Change
Chrgr_OpCtrl_Reg7( )	CHGR7	0x7c	0x07	R/W	R/W	Data Change
Chrgr_Status_Reg8( )	CHGR8	0x7d	0x08	R/W	R/W	Every Second
Chrgr_Fault_Reg9( )	CHGR9	0x7e	0x09	R/W	R/W	Every Second
Chrgr_Rev_RegA( )	CHGRA	0x7f	0x0a	R/W	R/W	Data Change

FUNCTIONAL DESCRIPTION

The bq27531-G1 measures the cell voltage, temperature, and current to determine battery SOC. The bq27531-G1 monitors charge and discharge activity by sensing the voltage across a small-value resistor (5 mΩ to 20 mΩ typ.) between the SRP and SRN pins and in series with the cell. By integrating charge passing through the battery, the battery's SOC is adjusted during battery charge or discharge.

The total battery capacity is found by comparing states of charge before and after applying the load with the amount of charge passed. When an application load is applied, the impedance of the cell is measured by comparing the OCV obtained from a predefined function for present SOC with the measured voltage under load. Measurements of OCV and charge integration determine chemical state of charge and chemical capacity (Qmax). The initial Qmax values are taken from a cell manufacturers' data sheet multiplied by the number of parallel cells. It is also used for the value in **Design Capacity**. The bq27531-G1 acquires and updates the battery-impedance profile during normal battery usage. It uses this profile, along with SOC and the Qmax value, to determine *FullChargeCapacity( )* and *StateOfCharge( )*, specifically for the present load and temperature. *FullChargeCapacity( )* is reported as capacity available from a fully charged battery under the present load and temperature until *Voltage( )* reaches the **Terminate Voltage**. *NominalAvailableCapacity( )* and *FullAvailableCapacity( )* are the uncompensated (no or light load) versions of *RemainingCapacity( )* and *FullChargeCapacity( )* respectively.

The bq27531-G1 has two flags accessed by the *Flags( )* function that warns when the battery's SOC has fallen to critical levels. When *RemainingCapacity( )* falls below the first capacity threshold, specified in **SOC1 Set Threshold**, the *[SOC1] (State of Charge Initial)* flag is set. The flag is cleared once *RemainingCapacity( )* rises above **SOC1 Clear Threshold**.

When *Voltage( )* falls below the system shut down threshold voltage, **SysDown Set Volt Threshold**, the *[SYSDOWN]* flag is set, serving as a final warning to shut down the system. The SOC_INT also signals. When *Voltage( )* rises above **SysDown Clear Voltage** and the *[SYSDOWN]* flag has already been set, the *[SYSDOWN]* flag is cleared. The SOC_INT also signals such change. All units are in mV.

When the voltage is discharged to **Terminate Voltage**, the SOC will be set as 0.
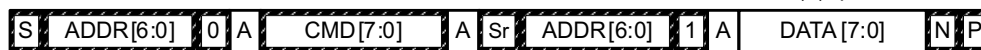
COMMUNICATIONS

I²C INTERFACE

The bq27531-G1 supports the standard I²C read, incremental read, quick read, one-byte write, and incremental write functions. The 7-bit device address (ADDR) is the most significant 7 bits of the hex address and is fixed as 1010101. The first 8 bits of the I²C protocol are, therefore, 0xAA or 0xAB for write or read, respectively.
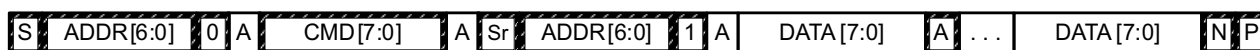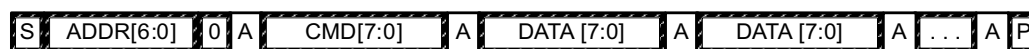

(S = Start, Sr = Repeated Start, A = Acknowledge, N = No Acknowledge, and P = Stop).

The quick read returns data at the address indicated by the address pointer. The address pointer, a register internal to the I²C communication engine, increments whenever data is acknowledged by the bq27531-G1 or the I²C master. "Quick writes" function in the same manner and are a convenient means of sending multiple bytes to consecutive command locations (such as two-byte commands that require two bytes of data).

The following command sequences are not supported:

Attempt to write a read-only address (NACK after data sent by master):
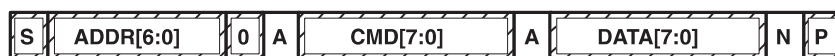
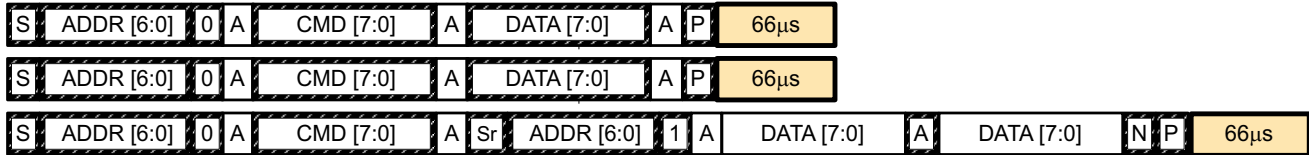Attempt to read an address above 0x6B (NACK command):

I²C Time Out
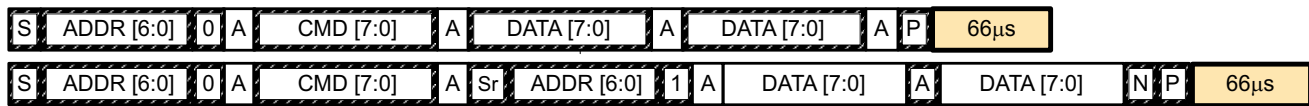
The I²C engine releases both SDA and SCL if the I²C bus is held low for 2 seconds. If the bq27531-G1 is holding the lines, releasing them frees them for the master to drive the lines. If an external condition is holding either of the lines low, the I²C engine enters the low-power sleep mode.

I²C Command Waiting Time

To ensure proper operation at 400 kHz, a $t_{(BUF)} \geq 66$ µs bus-free waiting time must be inserted between all packets addressed to the bq27531-G1 . In addition, if the SCL clock frequency (f_{SCL}) is > 100 kHz, use individual 1-byte write commands for proper data flow control. The following diagram shows the standard waiting time required between issuing the control subcommand the reading the status result. For read-write standard command, a minimum of 2 seconds is required to get the result updated. For read-only standard commands, there is no waiting time required, but the host must not issue any standard command more than two times per second. Otherwise, the gauge could result in a reset issue due to the expiration of the watchdog timer.

| S | ADDR [6:0] | 0 | A | CMD [7:0] | A | DATA [7:0] | A | P | 66µs |

| S | ADDR [6:0] | 0 | A | CMD [7:0] | A | DATA [7:0] | A | P | 66µs |

| S | ADDR [6:0] | 0 | A | CMD [7:0] | A | Sr | ADDR [6:0] | 1 | A | DATA [7:0] | A | DATA [7:0] | N | P | 66µs |

Waiting time inserted between two 1-byte write packets for a subcommand and reading results
(required for 100 kHz < $f_{SCL} \leq$ 400 kHz)

| S | ADDR [6:0] | 0 | A | CMD [7:0] | A | DATA [7:0] | A | DATA [7:0] | A | P | 66µs |

| S | ADDR [6:0] | 0 | A | CMD [7:0] | A | Sr | ADDR [6:0] | 1 | A | DATA [7:0] | A | DATA [7:0] | N | P | 66µs |

Waiting time inserted between incremental 2-byte write packet for a subcommand and reading results
(acceptable for $f_{SCL} \leq$ 100 kHz)

| S | ADDR [6:0] | 0 | A | CMD [7:0] | A | Sr | ADDR [6:0] | 1 | A | DATA [7:0] | A | DATA [7:0] | A |
| DATA [7:0] | A | DATA [7:0] | N | P | 66µs |

Waiting time inserted after incremental read

I²C Clock Stretching

A clock stretch can occur during all modes of fuel gauge operation. In SLEEP and HIBERNATE modes, a short clock stretch occurs on all I²C traffic as the device must wake-up to process the packet. In the other modes (BAT INSERT CHECK , NORMAL, SLEEP+) clock stretching only occurs for packets addressed for the fuel gauge. The majority of clock stretch periods are small as the I²C interface performs normal data flow control. However, less frequent yet more significant clock stretch periods may occur as blocks of Data Flash are updated. The following table summarizes the approximate clock stretch duration for various fuel gauge operating conditions.

Gauging Mode	Operating Condition / Comment	Approximate Duration
SLEEP HIBERNATE	Clock stretch occurs at the beginning of all traffic as the device wakes up.	≤ 4 ms
BAT INSERT CHECK NORMAL SLEEP+	Clock stretch occurs within the packet for flow control (after a start bit, ACK or first data bit).	≤ 4 ms
	Normal Ra table Data Flash updates.	24 ms
	Data Flash block writes.	72 ms
	Restored Data Flash block write after loss of power.	116 ms
	End of discharge Ra table Data Flash update.	144 ms

REFERENCE SCHEMATICS

SCHEMATIC

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
BQ27531YZFR-G1	Active	Production	DSBGA (YZF) | 15	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27531
BQ27531YZFR-G1.B	Active	Production	DSBGA (YZF) | 15	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27531
BQ27531YZFT-G1	Active	Production	DSBGA (YZF) | 15	250 | SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27531
BQ27531YZFT-G1.B	Active	Production	DSBGA (YZF) | 15	250 | SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27531

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.
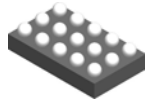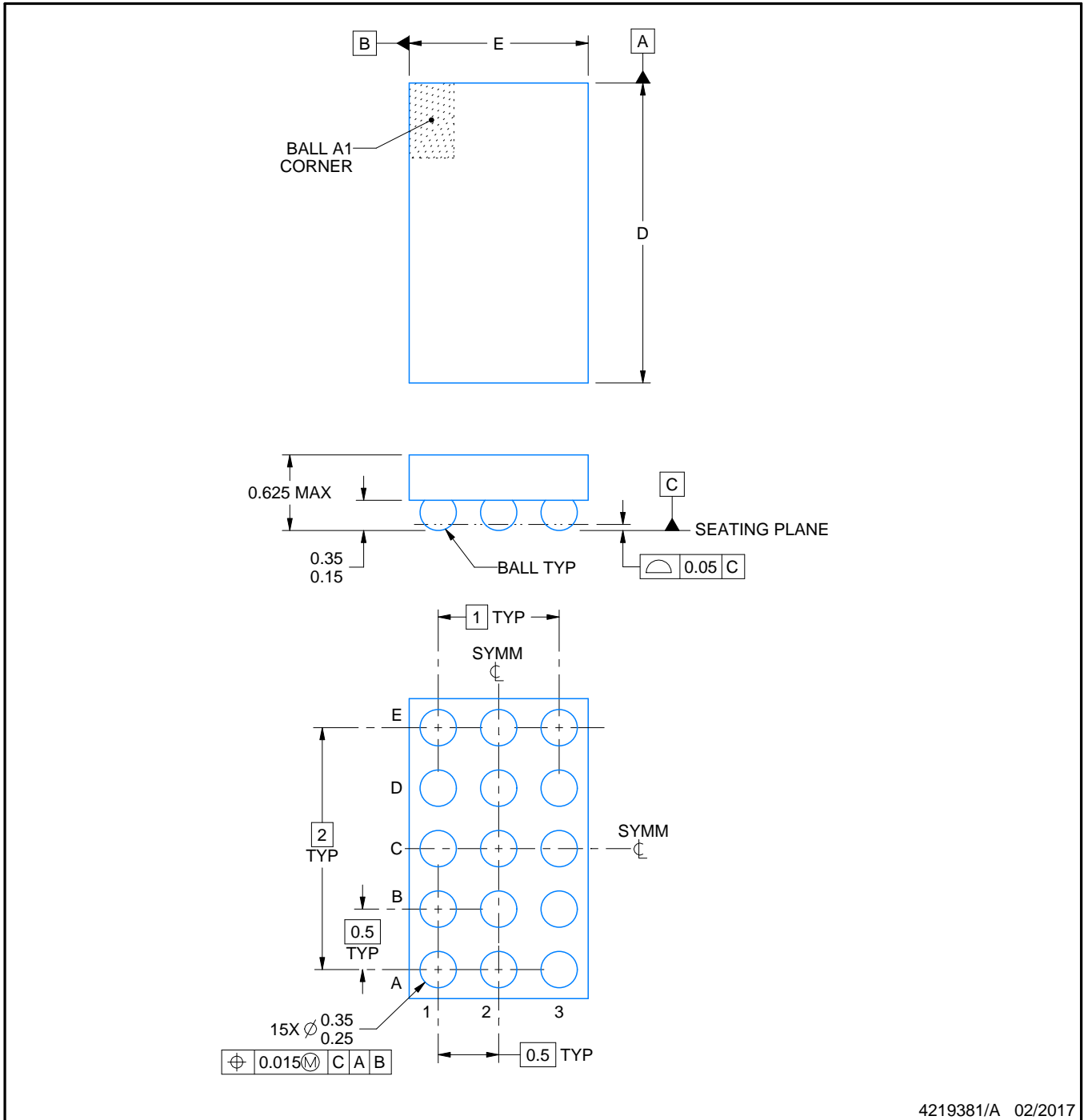
4219381/A   02/2017

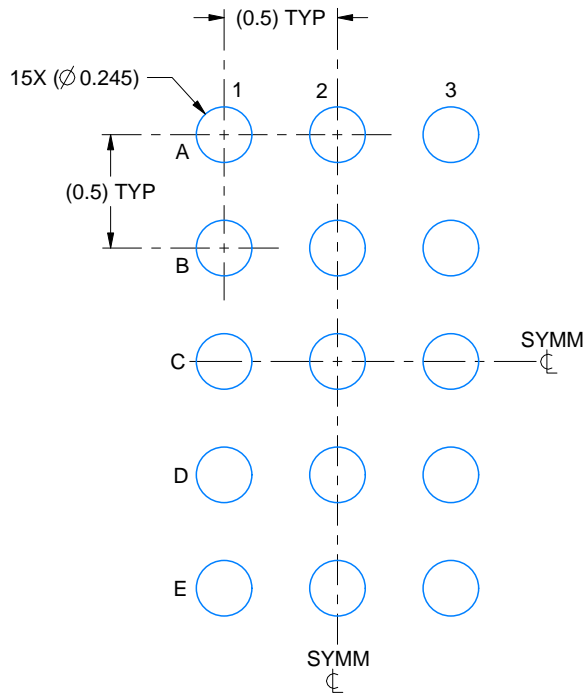NanoFree Is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
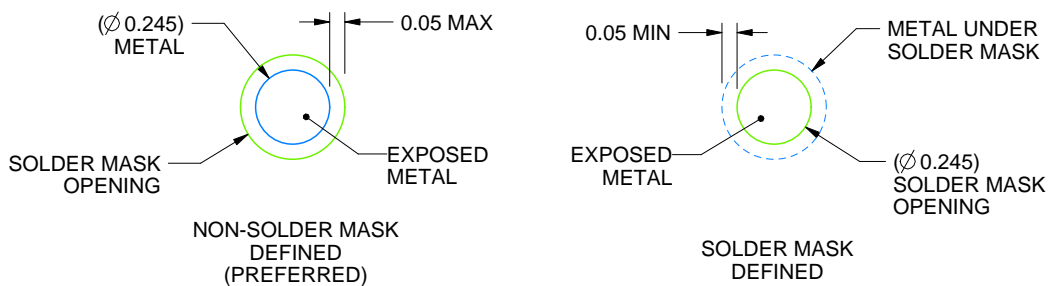3. NanoFree™ package configuration.

(0.5) TYP

15X (⌀ 0.245)

1   2   3

A

(0.5) TYP

B

C   SYMM ₵

D

E

SYMM ₵

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:30X

(⌀ 0.245) METAL

0.05 MAX

SOLDER MASK OPENING

EXPOSED METAL

NON-SOLDER MASK DEFINED (PREFERRED)

0.05 MIN

METAL UNDER SOLDER MASK

EXPOSED METAL

(⌀ 0.245) SOLDER MASK OPENING

SOLDER MASK DEFINED

SOLDER MASK DETAILS
NOT TO SCALE

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NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
   For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).
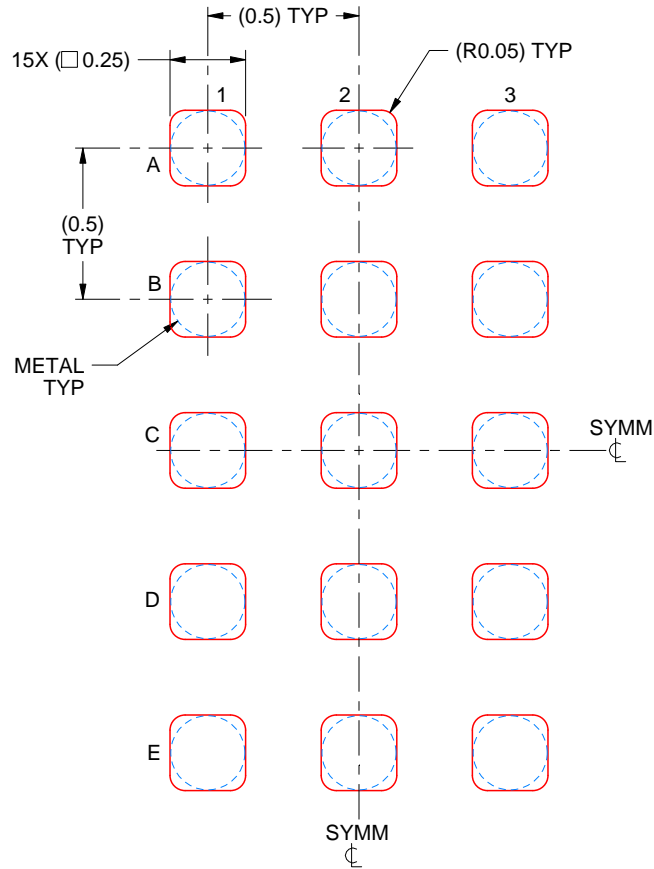
SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.